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Title: Residue-Free Fabrication of van der Waals Heterostructures of Two-Dimensional Materials

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Author Questionnaire

- 1. Microscopy:** Does your protocol require the use of a dissecting or stereomicroscope for performing a complex dissection, microinjection technique, or something similar? **No**

- 2. Software:** Does the part of your protocol being filmed include step-by-step descriptions of software usage? **No**

- 3. Filming location:** Will the filming need to take place in multiple locations? **No**

Current Protocol Length

Number of Steps: 13

Number of Shots: 18

Introduction

Videographer: Obtain headshots for all authors available at the filming location.

- 1.1. **Changho Kim:** We aim to develop a residue-free fabrication method for 2D heterostructures that avoids exposure to any residues and temperature changes, while ensuring the devices remain clean and high quality.
 - 1.1.1. INTERVIEW: Named talent says the statement above in an interview-style shot, looking slightly off-camera. *Suggested B-roll: 2.3.1*

What are the current experimental challenges?

- 1.2. **Minyoung Lee:** Transferring individual 2D flakes for multi-stacked heterostructures is technically challenging, and polymers or solvents often leave residues at the interface, disrupting clean stacking between layers.
 - 1.2.1. INTERVIEW: Named talent says the statement above in an interview-style shot, looking slightly off-camera. *Suggested B-roll: 3.1.1*

What significant findings have you established in your field?

- 1.3. **Changho Kim:** We established a novel method that enables precise 2D heterostructure assembly using only van der Waals forces through bottom-up, top-down, and modular stacking techniques.
 - 1.3.1. INTERVIEW: Named talent says the statement above in an interview-style shot, looking slightly off-camera. *Suggested B-roll: 4.2.1*

What research questions will your laboratory focus on in the future?

- 1.4. **Jae Hun Seol:** We plan to apply this method to various applications, such as optical or gas sensors, that require complex heterostructures with clean and high-quality interfaces.
 - 1.4.1. INTERVIEW: Named talent says the statement above in an interview-style shot, looking slightly off-camera. *Suggested B-roll: 2.2.1*

Videographer: Obtain headshots for all authors available at the filming location.

Protocol

2. Acquiring the Residue-Free Region

Demonstrator: Minyoung Lee

Videographer: Please film the steps 2.1 to 2.5

2.1. To begin, prepare a piece of bulk crystal using a cotton swab and a razor blade [1].

2.1.1. WIDE: Talent using a razor blade and cotton swab to extract a section of bulk crystal.

2.2. Attach the prepared crystal onto the adhesive surface of a pre-exfoliation stamp [1] and place another pre-exfoliation stamp on top of the crystal to form a sandwich configuration [2].

2.2.1. Talent placing the crystal onto the sticky surface of the first stamp.

2.2.2. Talent aligning and pressing a second stamp over the crystal to make a sandwich.

2.3. Gently exfoliate the sandwiched crystal [1] and repeat this process 3 to 5 times to obtain a clean and uniform sub-micron-thick crystal [2].

2.3.1. Talent lifting and pressing the stamps repeatedly to exfoliate the crystal.

2.3.2. Shot of a clean and uniform sub-micron-thick crystal.

2.4. Now, place the pre-exfoliated crystal onto the sample stage [1] and secure the tape stamp with a tilt angle of at least 5 degrees onto the magnetic plate of the stamp manipulator using a magnet [2].

2.4.1. Talent positioning the exfoliated crystal on the flat sample stage.

2.4.2. Talent attaching the tilted tape stamp to the magnetic holder using a small magnet.

2.5. Align the tape stamp above the pre-exfoliated crystal by adjusting the sample stage [1].

2.5.1. Talent slowly turning knobs or sliding controls to center the tape stamp over the crystal.

AUTHOR'S NOTE: Please use the shot showing adjustment of the sample stage's x-axis. Although we also recorded a version adjusting the stamp manipulator's x-axis, this should not be used

- 2.6. Attach the tape stamp to the top surface of the crystal by adjusting the stamp manipulator in the negative Z direction and gently exfoliate the thin residue-free region by adjusting the stamp manipulator in the positive Z direction [1].

2.6.1. SCOPE: Video 1.avi 00:00 – 00:11

- 2.7. Adhere the residue-free region firmly to the substrate by adjusting the stamp manipulator in the negative Z direction [1].

2.7.1. SCOPE: Video 2.avi 00:00 – 00:02 and FILE: Video 3.avi 00:04 – 00:04

- 2.8. Then, exfoliate the single flake by adjusting the stamp manipulator in the positive Z direction [1].

2.8.1. SCOPE: Video 2.avi 00:04 – 00:08 and FILE: Video 3.avi 00:06 – 00:12

3. Fabrication of Residue-Free van der Waals Heterostructure Assemblies Through Bottom-Up Stacking Process

- 3.1. Pick up the molybdenum disulfide flake with the MoS₂ (M-O-S-2) residue-free stamp [1-TXT] and release it onto the h-BN (H-B-N) flake, to assemble the structure [2-TXT].

3.1.1. SCOPE: Video 4.avi 00:00 – 00:05. TXT: MoS₂: Molybdenum Disulfide

3.1.2. SCOPE: Video 4.avi 00:08 – 00:14 TXT: h-BN: Hexagonal Boron Nitride

- 3.2. Pick up another h-BN flake and release it on the MoS₂ and h-BN structure [1].

3.2.1. SCOPE: Video 4.avi 00:16 – 00:31

- 3.3. Next, pick up the h-BN flake using the MoS₂ residue-free stamp [1].

3.3.1. SCOPE: Video 5.avi 00:04 – 00:07

- 3.4. Use the picked-up HBN flake to cover the MoS₂ flake, and then pick up the MoS₂ flake with the already picked-up h-BN flake, forming a h-BN and MoS₂ structure [1].

3.4.1. SCOPE: Video 5.avi 00:08 – 00:12

3.5. Finally, release the combined structure onto another h-BN flake [1] and then release the Hetero B onto the Hetero A [2].

3.5.1. SCOPE: Video 5.avi 00:13 – 00:20

3.5.2. SCOPE: Video 6.avi 00:04 – 00:11

Results

4. Results

4.1. The symmetrical hexagonal atomic structure of residue-free MoS₂ was confirmed using high-resolution transmission electron microscopy and selected area electron diffraction pattern analysis [1].

4.1.1. LAB MEDIA: Figure 7.

4.2. Energy-dispersive X-ray spectroscopy mapping revealed strong molybdenum and sulfur signals [1] and minimal carbon and oxygen, confirming the absence of polymer residue and oxidation on the molybdenum disulfide flakes [2].

4.2.1. LAB MEDIA: Figure 7A. *Video editor: Highlight the EDS maps showing MO and S images.*

4.2.2. LAB MEDIA: Figure 7A. *Video editor: Highlight the EDS maps showing C and O images.*

4.3. Atomic force microscopy analysis showed that the thicknesses of transferred h-BN and MoS₂ flakes were 18.34 nanometers and 5.27 nanometers, respectively [1].

4.3.1. LAB MEDIA: Figure 8. *Video editor: Highlight the values 18.34 nm and 5.27 nm in B and E.*

4.4. The root-mean-square roughness values of 0.143 nanometers for h-BN and 0.153 nanometers for MoS₂ confirmed excellent flatness with minimal surface irregularities [1].

4.4.1. LAB MEDIA: Figure 8. *Video editor: Highlight the blue boxes displaying the Rq values 0.143 nm and 0.153 nm in B and E.*

4.5. Raman spectroscopy analysis revealed peak positions at approximately 1365 and 383 inverse centimeters for h-BN and MoS₂, respectively, indicating strain-free transfer [1].

4.5.1. LAB MEDIA: Figure 8. *Video editor: Highlight the peaks E2g in C and E12g in F.*

4.6. Distinct manipulation methods allowed successful assembly of the heterostructures via both bottom-up and top-down stacking [1].

- 4.6.1. LAB MEDIA: Figure 9. *Video editor: Highlight the labeled regions “Hetero A” and “Hetero B” in panels A and B.*

- 4.7. The assembled heterostructures exhibited randomly distributed gas-filled blisters at the heterointerface without any applied force [1].
- 4.7.1. LAB MEDIA: Figure 10B. *Video editor: Highlight the optical image of “as assembled” showing “gas blisters”.*

- 4.8. Application of increasing forces from 30 to 1000 nano-newtons progressively reduced blister size and count [1].
- 4.8.1. LAB MEDIA: Figure 10B. *Video editor: Sequentially highlight the images and the corresponding graphs from “30” to “1000 nN”.*

Pronunciation Guide:

1. van der Waals

Pronunciation link (Merriam-Webster):

<https://www.merriam-webster.com/dictionary/van%20der%20Waals>

IPA: /væn dər 'vɔlz/

Phonetic Spelling: van-der-VAHLZ

2. heterostructure

Pronunciation link (Merriam-Webster — hetero-):

<https://www.merriam-webster.com/dictionary/hetero>
(and structure)

IPA: /,hɛtərəʊ'strʌktʃər/ → American /,hɛtərə'strʌktʃə/

Phonetic Spelling: HET-uh-roh-STRUK-cher

3. molybdenum disulfide (MoS₂)

Pronunciation link (Merriam-Webster — molybdenum):

<https://www.merriam-webster.com/dictionary/molybdenum>

IPA: /mə'libdə,nəm dɑɪ'sʌlfɑɪd/

Phonetic Spelling: muh-LIB-duh-num die-SUL-fide

4. hexagonal boron nitride (h-BN)

Pronunciation link (Merriam-Webster — hexagonal):

<https://www.merriam-webster.com/dictionary/hexagonal>

IPA: /hɛk'sæɡənəl 'bɔrən naɪ'traɪd/

Phonetic Spelling: hek-SAG-uh-nul BOR-on NY-tride

5. exfoliate

Pronunciation link (Merriam-Webster):

<https://www.merriam-webster.com/dictionary/exfoliate>

IPA: /ɪk'sfoʊli,et/

Phonetic Spelling: ik-SFOH-lee-ayt

6. nanometer

Pronunciation link (Merriam-Webster):

<https://www.merriam-webster.com/dictionary/nanometer>

IPA: /'nænə,mi:tər/

Phonetic Spelling: NAN-uh-mee-ter

7. atomic force microscopy

Pronunciation link (Merriam-Webster — atomic):

<https://www.merriam-webster.com/dictionary/atomic>

Pronunciation link (Merriam-Webster — microscopy):

<https://www.merriam-webster.com/dictionary/microscopy>

IPA: /ə'tamɪk fɔrs maɪ'kræskəpi/

Phonetic Spelling: uh-TOM-ik force my-KROS-kuh-pee

8. Raman spectroscopy

Pronunciation link (Merriam-Webster — Raman):

<https://www.merriam-webster.com/dictionary/raman>

Pronunciation link (Merriam-Webster — spectroscopy):

<https://www.merriam-webster.com/dictionary/spectroscopy>

IPA: /'rɑ:mən spek'træskəpi/

Phonetic Spelling: RAH-man spek-TRAW-skuh-pee

9. energy-dispersive X-ray spectroscopy (EDS/XPS)

Pronunciation link (Merriam-Webster — dispersive):

<https://www.merriam-webster.com/dictionary/dispersive>

IPA: /'ɛnədʒi dɪ'spɜrsɪv ɛks reɪ spek'træskəpi/

Phonetic Spelling: EN-er-jee dis-PUR-siv ex RAY spek-TRAW-skuh-pee

10. nanonewton

Pronunciation link (Merriam-Webster — newton):

<https://www.merriam-webster.com/dictionary/newton>

IPA: /'nænə'nuˌtən/

Phonetic Spelling: NAN-uh-NEW-ton